

# ALM-1106

GPS Low Noise amplifier with Variable bias current and Shutdown function



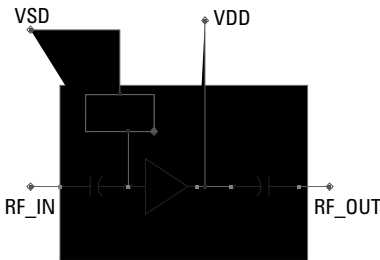
## Data Sheet

### Description

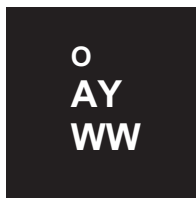
Avago Technologies’s ALM-1106 is a LNA designed for GPS/ISM/Wimax applications in the (0.9-3.5)GHz frequency range. The LNA uses Avago Technologies’s proprietary GaAs Enhancement-mode pHEMT process to achieve high gain operation with very low noise figures and high linearity. Noise figure distribution is very tightly controlled. Gain and supply current are guaranteed parameters. A CMOS compatible shutdown pin is included to turn the LNA off and provide a variable bias.

The ALM-1106 LNA is useable down to 1V operation. It achieves low noise figures and high gain even at 1V, making it suitable for use in critical low power GPS/ISM band applications.

### Simplified Schematic

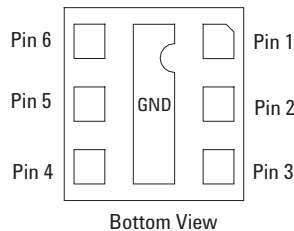


Surface Mount  
2.0 x 2.0 x 1.1 mm<sup>3</sup>



Note:  
Package marking provides Orientation and identification  
“A” = Product Code  
“Y” = Year  
“WW” = Work Week

### Pin Configuration



LNA I/O's :  
1. NC                    4. VSD  
2. RF\_IN                5. RF\_OUT  
3. NC                    6. VDD  
BOTTOM PADDLE : GND

### Features

- Advanced GaAs E-pHEMT
- Low Noise: 0.8 dB typ
- High Gain : 14.3 dB typ
- Low component count
- High IIP3 and IP1dB
- Wide Supply Voltage: 1V to 3.6V
- Shutdown current : < 0.1uA
- CMOS compatible shutdown pin (VSD) current @ 2.85V : 90uA
- Adjustable bias current via one single external resistor/voltage
- Small Footprint: 2x2mm<sup>2</sup>
- Low Profile: 1.1 mm typ
- Ext matching for non-GPS freq band operation

### Specifications (25 deg): At 1.575GHz, 2.85V 8mA (Typ)

- Gain = 14.3 dB (Typ)
- NF = 0.8 dB (Typ)
- IIP3 = 4.7 dBm (Typ)
- IP1dB = 1.8 dBm (Typ)
- S11 = -11.8 dB (Typ)
- S22 = -12.4 dB (Typ)

### Typical performance @ 1.0V supply

S21 = 12.3dB  
NF = 1.0dB  
Ids = 3.6mA

Note:  
Measurements obtained using demoboard described in Figure 4.

## Absolute Maximum Ratings [1]

Symbol	Parameter	Units	Absolute Maximum
VDS	Drain - Source Voltage[2]	V	3.6
IDS	Drain Current[2]	mA	15
Pdiss	Total Power Dissipation [3]	mW	54
Pin max.	RF Input Power	dBm	+10
TCH	Channel Temperature	°C	150
TSTG	Storage Temperature	°C	-65 to 150
qch_b	Thermal Resistance [4]	°C/W	232

### Notes:

1. Operation of this device above any one of these parameters may cause permanent damage.
2. Assuming DC quiescent conditions.
3. Board (package belly) temperature  $T_B$  is 25°C. Derate 4.32mW/°C for  $T_B > 137$  °C.
4. Channel-to-board thermal resistance measured using 150°C Liquid Crystal Measurement method.

## Product Consistency Distribution Charts [5,6]

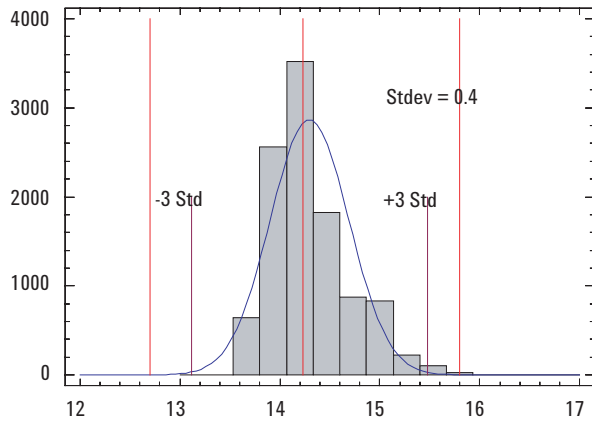


Figure 1. Gain @ 1.575GHz; LSL = 12.7dB, Nominal = 14.3dB, USL = 15.8dB

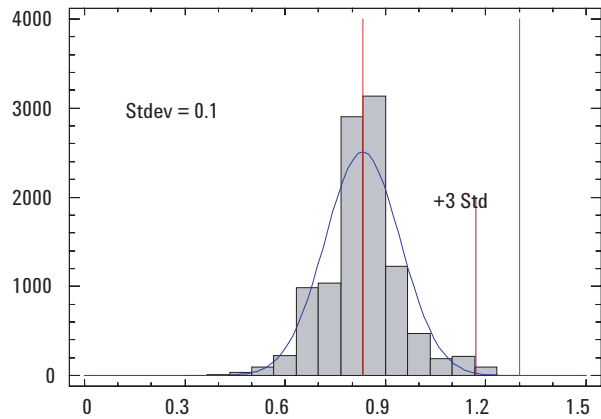


Figure 2. NF @ 1.575GHz; Nominal = 0.8dB, USL = 1.3dB

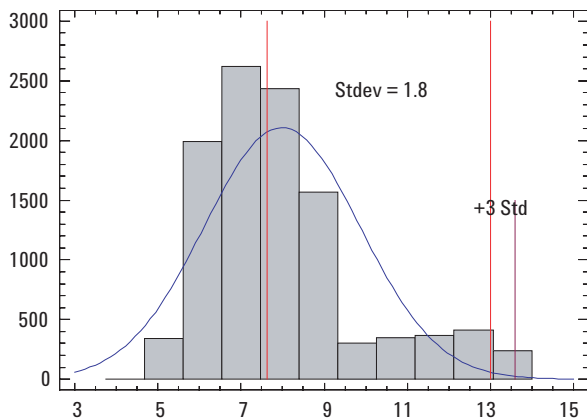


Figure 3. Ids @ 1.575GHz; Nominal = 8mA, USL = 13mA

### Notes:

5. Distribution data sample size is 10K samples taken from 3 different wafers and 3 different lots. Future wafers allocated to this product may have nominal values anywhere between the upper and lower limits.
6. Measurements are made on production test board, which represents a trade-off between optimal Gain, NF, IIP3, IP1dB and VSWR. Circuit losses have been de-embedded from actual measurements.

## Electrical Specifications

$T_A = 25\text{ }^\circ\text{C}$ , DC bias for RF parameter is  $V_{DD} = V_{SD} = +2.85\text{V}$  @ 8mA (unless otherwise specified)

**Table 1. Performance table at nominal operating conditions**

$V_{DD} = V_{SD} = +2.85\text{V}$ ,  $R_1 = 18\text{K Ohm}$ ,  $\text{Freq} = 1.575\text{GHz}$  – Typical Performance

Symbol	Parameter and Test Condition	Units	Min.	Typ	Max.
G	Gain	dB	12.7	14.3	15.8
NF	Noise Figure	dB	-	0.8	1.3
IP1dB	Input 1dB Compressed Power	dBm		1.8	
IIP3	Input 3rd Order Intercept Point (2-tone @ $F_c \pm 2.5\text{MHz}$ )	dBm		4.7	
S11	Input Return Loss	dB		-11.8	
S22	Output Return Loss	dB		-12.4	
I <sub>ds</sub>	Supply Current	mA		8	13
I <sub>sh</sub>	Shutdown Current @ $V_{SD} = 0\text{V}$	uA		0.1	
V <sub>ds</sub>	Supply Voltage	V		2.85	
IP1dB <sub>1710M</sub>	Out of Band IP1dB (DCS 1710MHz) blocking	dBm		2.9	
IIP3 <sub>OUT</sub>	Out of Band IIP3 (DCS 1775MHz & 1950MHz)	dBm		5.5	

**Table 2 – Typical performance at low operation voltages with R1 (see Fig 5) set to 0 Ohm**

$V_{DD} = +2\text{V}$ ,  $V_{DD} = +1.5\text{V}$  &  $V_{DD} = +1.0\text{V}$ ,  $\text{Freq} = 1.575\text{GHz}$  – Typical Performance ( $V_{SD} = V_{DD}$ ,  $R_1 = 0\text{ Ohm}$ )

Symbol	Parameter and Test Condition	Units	V <sub>DD</sub> =2V	V <sub>DD</sub> =1.5V	V <sub>DD</sub> =1.0V
G	Gain	dB	15	14.2	12.3
NF	Noise Figure	dB	0.8	0.9	1
IP1dB	Input 1dB Compressed Power	dBm	-1.4	-2.4	-3.8
IIP3	Input 3rd Order Intercept Point (2-tone @ $F_c \pm 2.5\text{MHz}$ )	dBm	7.3	4.9	5.2
S11	Input Return Loss	dB	-13.8	-11.5	-8
S22	Output Return Loss	dB	-15.5	-14.5	-11.7
I <sub>ds</sub>	Supply Current	mA	13	7.5	3.6
I <sub>sh</sub>	Shutdown Current @ $V_{SD} = 0\text{V}$	uA	0.1	0.1	0.1
V <sub>ds</sub>	Supply Voltage	V	2	1.5	1.0
IP1dB <sub>1710M</sub>	Out of Band IP1dB (DCS 1710MHz) blocking	dBm	-0.3	-1.9	-2.9
IIP3 <sub>OUT</sub>	Out of Band IIP3 (DCS 1775MHz & 1950MHz)	dBm	8.7	5.8	3

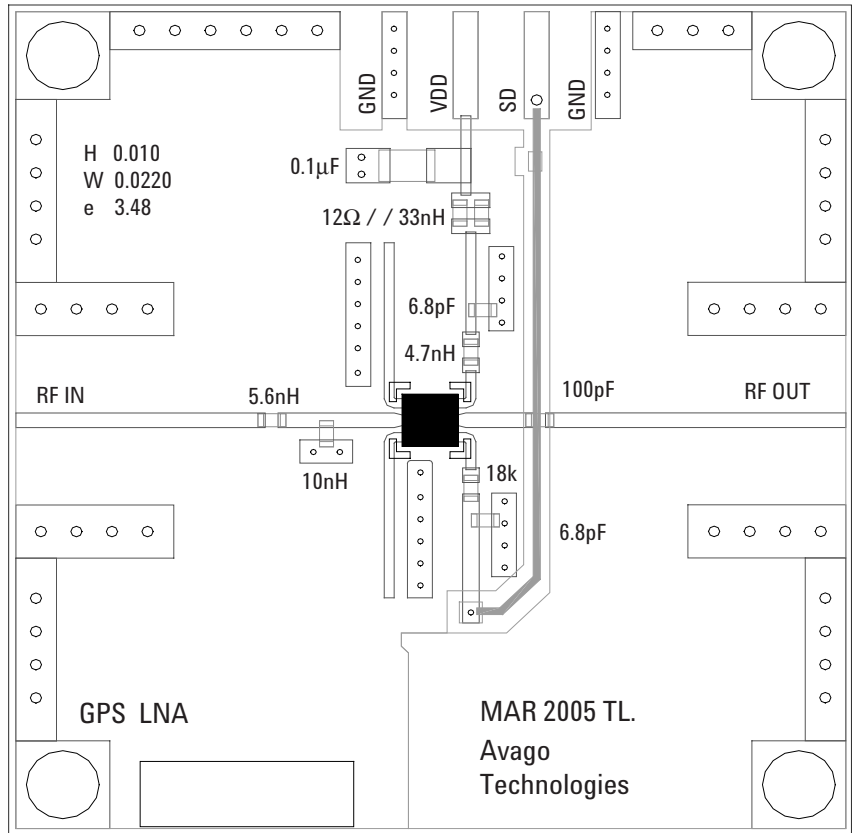


Figure 4. Demoboard and Application Circuit Components

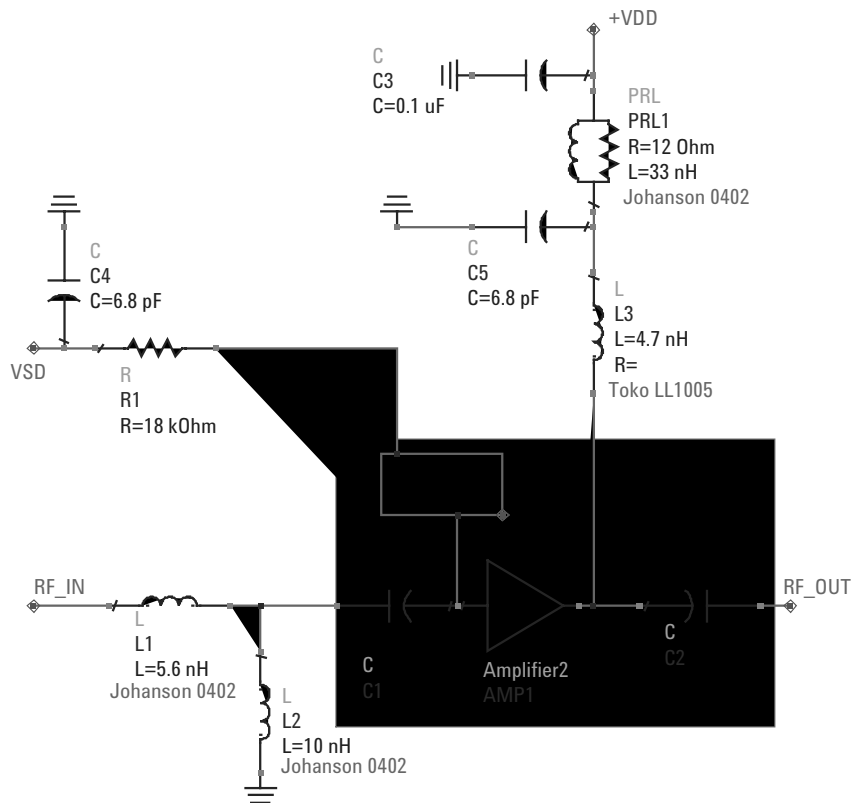
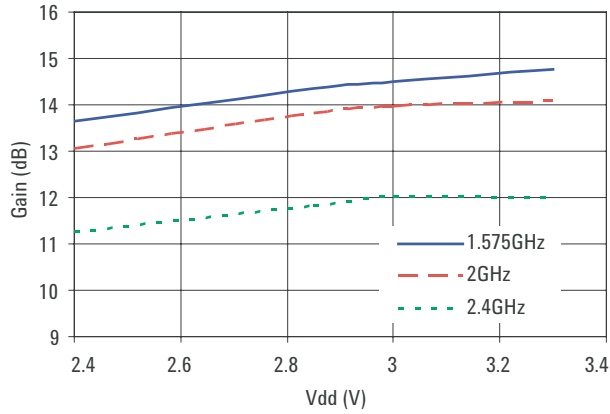


Figure 5. Demoboard schematic

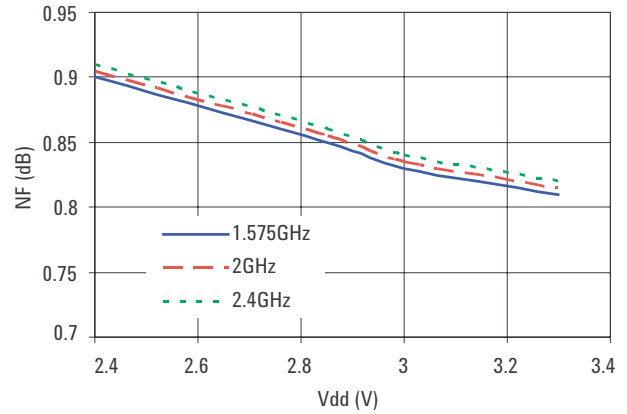
Notes

- L1 and L2 form the input matching network. The LNA module has a integrated coupling and DC-blocking capacitors at the input and output. Best noise performance is obtained using high-Q wirewound inductors. This circuit demonstrates that low noise figures are obtainable with standard 0402 chip inductors. Replacing L1, L2 and L3 with high-Q wirewound inductors (eg. Cilcraft 0402CS series) will yield 0.1dB lower NF and 0.6dB higher Gain.
- L3 is an output matching inductor.
- C5 is a RF bypass capacitor.
- PRL1 is a network that isolates the measurement demoboard from external disturbances. C3 and C4 mitigates the effect of external noise pickup on the VSD and VDD lines. These components are not required in actual operation.
- Bias control is achieved by either varying the VSD voltage without R1 or fixing the VSD voltage to VDD and varying R1. Typical value for R1 is 18k Ohm for 8mA total current at VDD=+2.85V.
- Higher gain and IP3 performance can be obtained by increasing the supply current. This can be achieved by reducing the value for R1 to obtain desired current.
- For low voltage operation such as 1.5V or 1.0V, the R1 may be omitted and VSD connected directly to the supply pins.

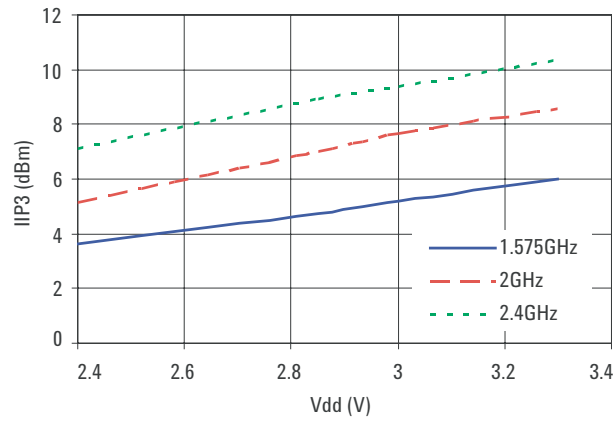
**ALM-1106 Typical Performance Curves, R1 = 18K Ohm (At 25°C unless specified otherwise)**



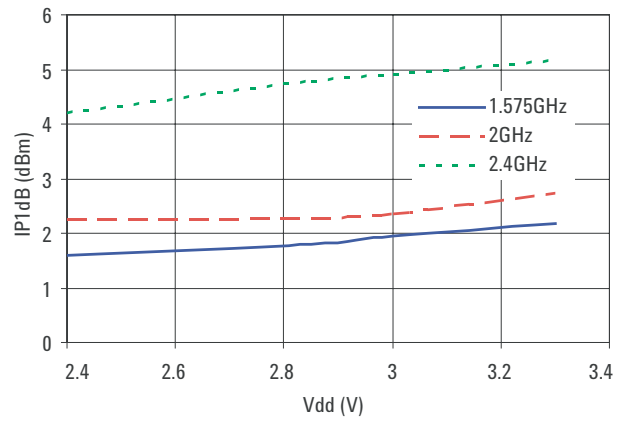
**Figure 6. Gain vs Vdd vs Freq**



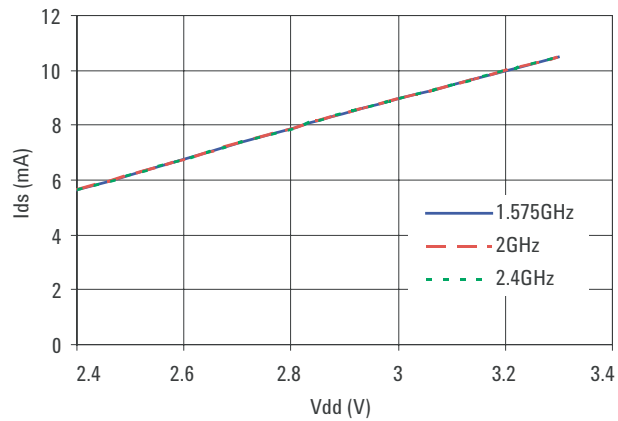
**Figure 7. NF vs Vdd vs Freq**



**Figure 8. IIP3 vs Vdd vs Freq**



**Figure 9. IP1dB vs Vdd vs Freq**



**Figure 10. Ids vs Vdd vs Freq**

**ALM-1106 Typical Performance Curves, R1 = 18K Ohm (At 25°C unless specified otherwise)**

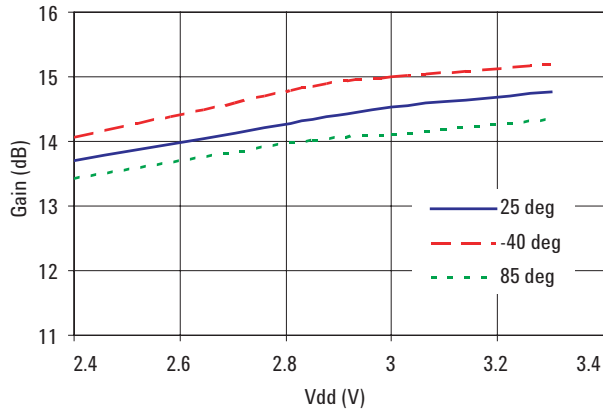


Figure 11. Gain vs Vdd vs Temp

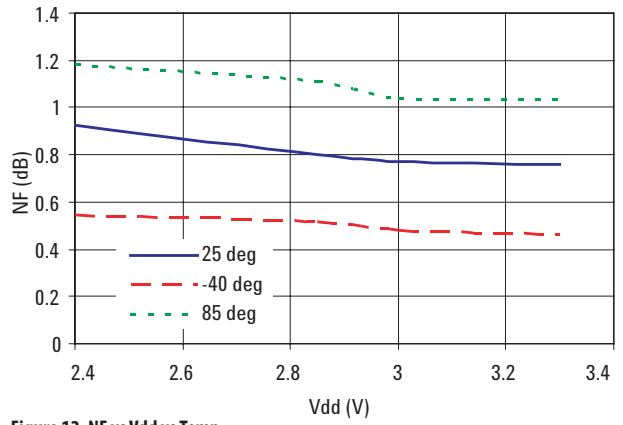


Figure 12. NF vs Vdd vs Temp

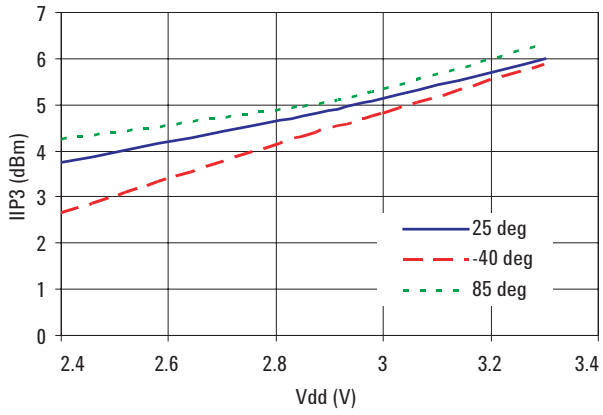


Figure 13. IIP3 vs Vdd vs Temp

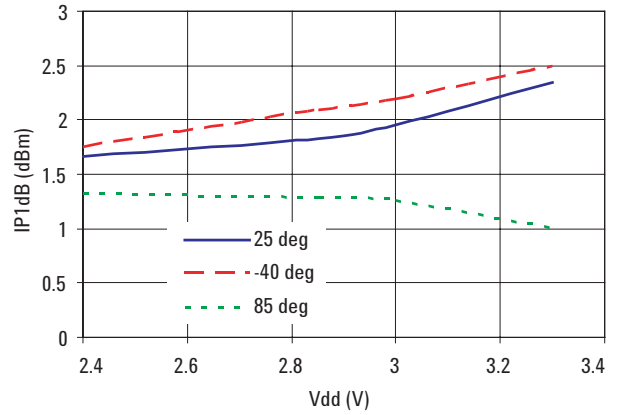


Figure 14. IP1dB vs Vdd vs Temp

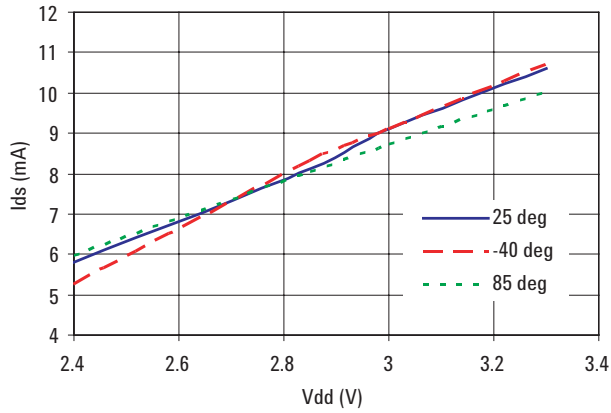


Figure 15. Ids vs Vdd vs Temp

**ALM-1106 Typical Scattering Parameters at 25°C, V<sub>DD</sub> = 2.85V, I<sub>DS</sub> = 8 mA**

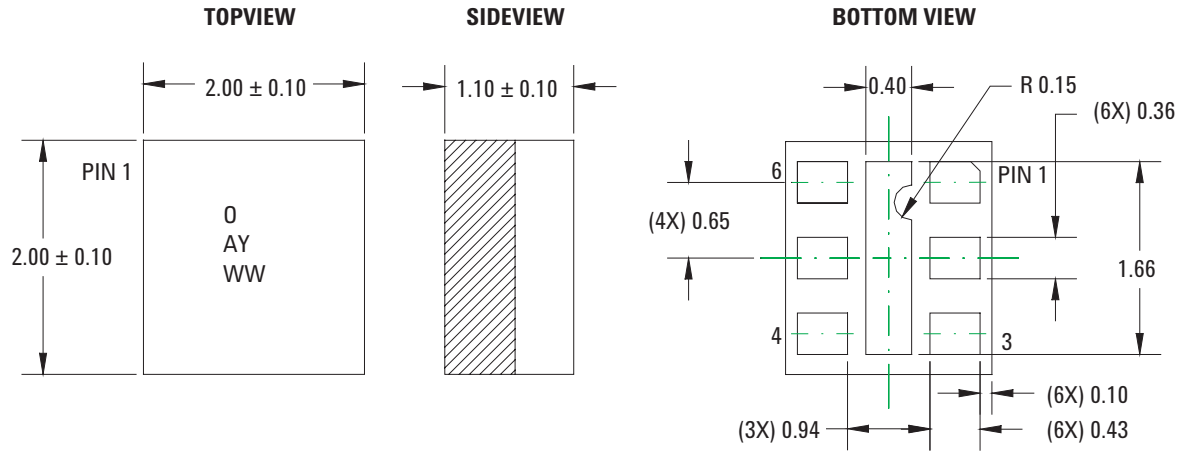
Freq. (GHz)	S11		S21		S12			S22		
	Mag.	Ang.	(dB)	Mag.	Ang.	(dB)	Mag.	Ang.	Mag.	Ang.
0.1	0.998	-4.7	15.01	5.633	176.7	-47.96	0.004	89.2	0.526	-5
0.5	0.946	-23.5	14.62	5.381	153.1	-34.42	0.019	78.6	0.503	-19
0.9	0.866	-40.4	13.72	4.854	134.1	-29.90	0.032	71.8	0.475	-31.9
1	0.843	-44.4	13.47	4.714	129.7	-29.37	0.034	70.5	0.468	-34.9
1.1	0.821	-48.2	13.20	4.573	125.5	-28.64	0.037	69.3	0.459	-37.9
1.2	0.8	-52	12.95	4.44	121.5	-27.96	0.04	68.5	0.451	-40.5
1.3	0.78	-55.8	12.69	4.31	117.6	-27.33	0.043	67.4	0.443	-43.2
1.4	0.757	-59.7	12.42	4.178	113.6	-26.94	0.045	66.5	0.435	-45.8
1.5	0.731	-63.4	12.13	4.039	109.7	-26.38	0.048	65.7	0.428	-48.2
1.6	0.705	-66.8	11.83	3.905	106.1	-26.02	0.05	64.8	0.421	-50.7
1.7	0.683	-69.7	11.55	3.78	102.9	-25.51	0.053	64.7	0.414	-52.8
1.8	0.663	-71.6	11.29	3.669	99.5	-25.19	0.055	63.9	0.408	-55.5
1.9	0.643	-73.4	10.99	3.544	96	-24.73	0.058	63.1	0.399	-58
2	0.623	-75.3	10.48	3.343	97	-24.58	0.059	66.3	0.398	-58.8
2.1	0.603	-77.2	10.25	3.253	93.5	-24.15	0.062	65.5	0.398	-59.6
2.2	0.583	-79	10.01	3.165	90.2	-23.74	0.065	64.6	0.397	-60.3
2.3	0.563	-80.9	9.77	3.079	87	-23.48	0.067	63.8	0.396	-61.1
2.4	0.543	-82.8	9.49	2.983	83.8	-23.10	0.07	63	0.396	-62.1
2.5	0.522	-85.3	9.23	2.895	81.1	-22.73	0.073	62.3	0.395	-62.7
3	0.434	-105.2	7.95	2.498	66.6	-21.21	0.087	56.9	0.345	-74.4
3.5	0.334	-119.5	6.47	2.105	57.3	-20.26	0.097	54	0.324	-86.8
4	0.302	-132.1	6.25	2.054	48.8	-18.42	0.12	53.7	0.271	-108
4.5	0.297	-141.8	5.50	1.883	33.1	-16.95	0.142	43.4	0.265	-113.3
5	0.274	-157.1	4.44	1.667	23.9	-15.97	0.159	38	0.259	-118.6
5.5	0.254	-170.1	3.63	1.519	16.1	-15.04	0.177	33.7	0.26	-133.2
6	0.211	178.7	2.82	1.383	6.3	-14.11	0.197	25.3	0.249	-142.7
6.5	0.204	165.4	1.89	1.243	-0.7	-13.64	0.208	16.7	0.263	-154.7
7	0.189	137.1	1.56	1.197	-5.4	-13.27	0.217	12.7	0.306	-171.3
7.5	0.193	117.3	1.03	1.126	-14.4	-12.88	0.227	9.5	0.31	179.8
8	0.206	90.6	0.87	1.105	-22.2	-12.40	0.24	4.7	0.314	170.8

**ALM-1106 Typical Noise Parameters,  $V_{DD} = 2.85V$ ,  $I_{DS} = 8mA$** 

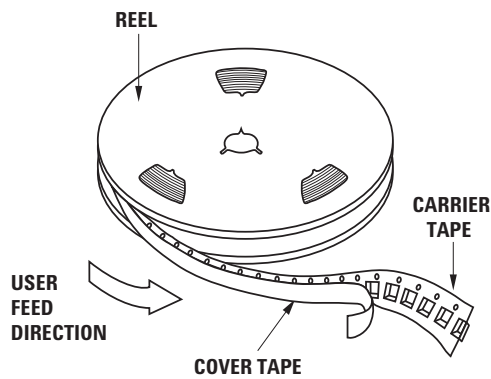
<b>Freq (GHz)</b>	<b>Fmin (dB)</b>	<b>Gopt Mag.</b>	<b>Gopt Ang.</b>	<b>Rn/50</b>	<b>NF @ 50dB</b>
0.5	0.53	0.64	13.8	0.41	1.46
0.9	0.65	0.69	32.2	0.28	1.07
1.5	0.8	0.71	47.4	0.24	1.22
1.7	0.82	0.69	58.1	0.22	1.14
2	0.91	0.68	59.5	0.23	1.1
2.4	0.93	0.64	71.3	0.27	1.72
3	1.21	0.52	99.2	0.16	1.45
3.5	1.33	0.44	135.8	0.12	1.6
4	1.69	0.35	161.3	0.08	1.27
4.5	1.73	0.31	171.3	0.06	1.47
5	1.82	0.32	-179.6	0.06	1.65
5.5	1.98	0.34	-171.2	0.08	2.16
5.8	2.37	0.43	-174.8	0.14	2.88



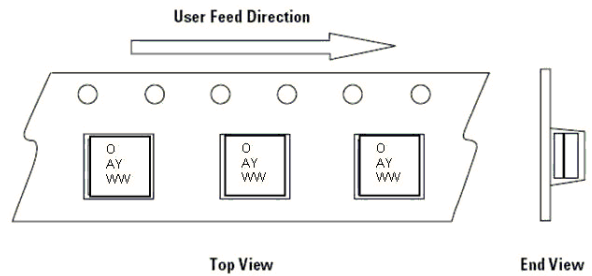
## Package Dimensions



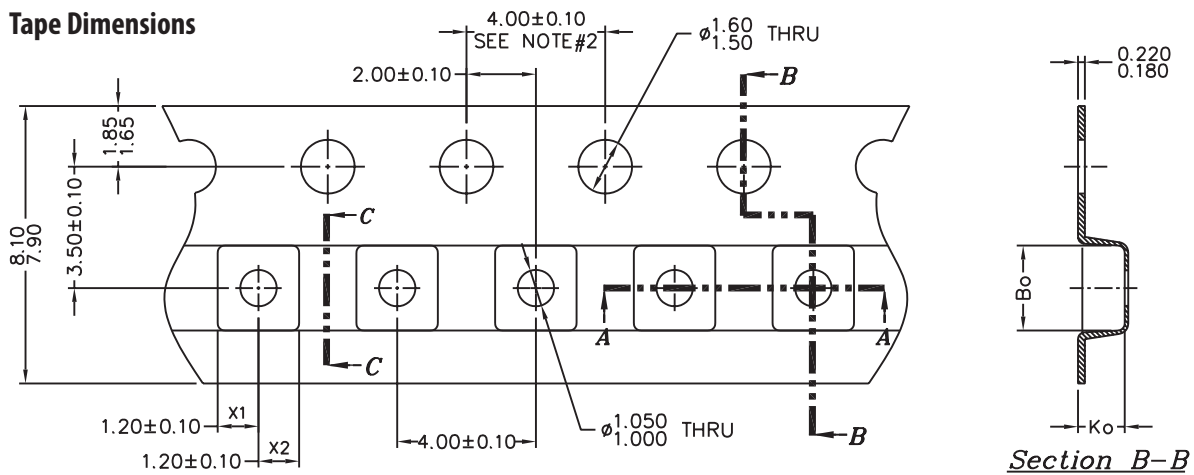
## Device Orientation



Existing Thermal Ground to pad clearance = 0.16mm  
 Samsung Thermal Ground to pad min clearance = 0.25mm



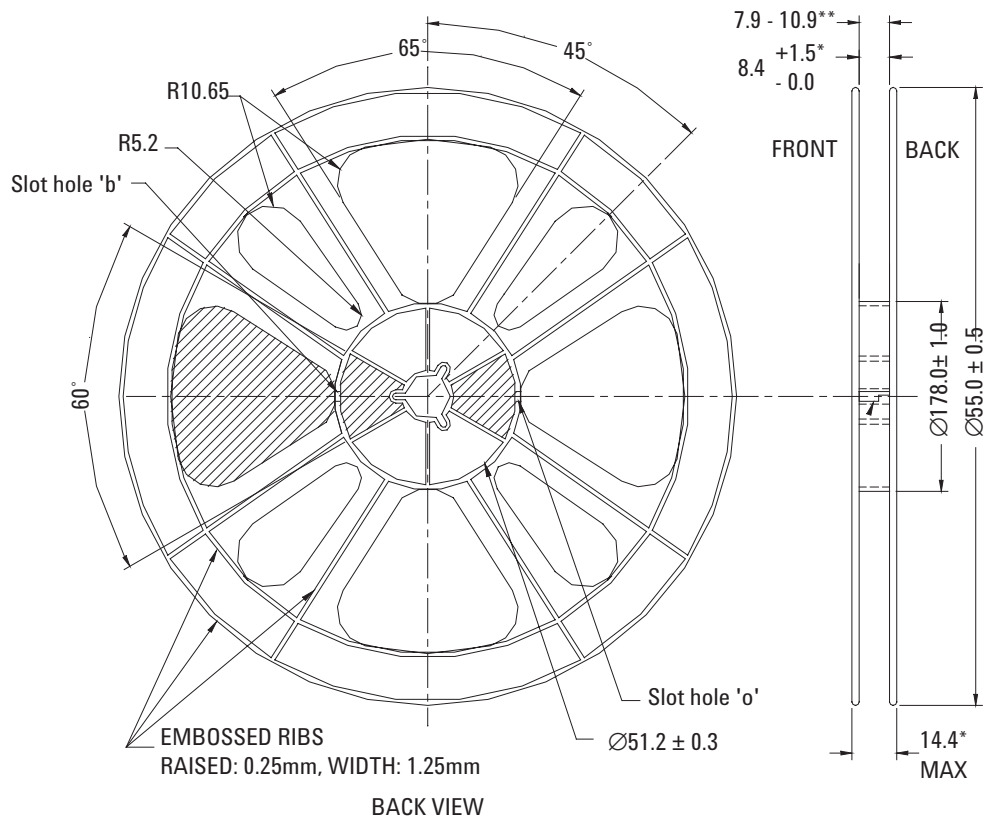
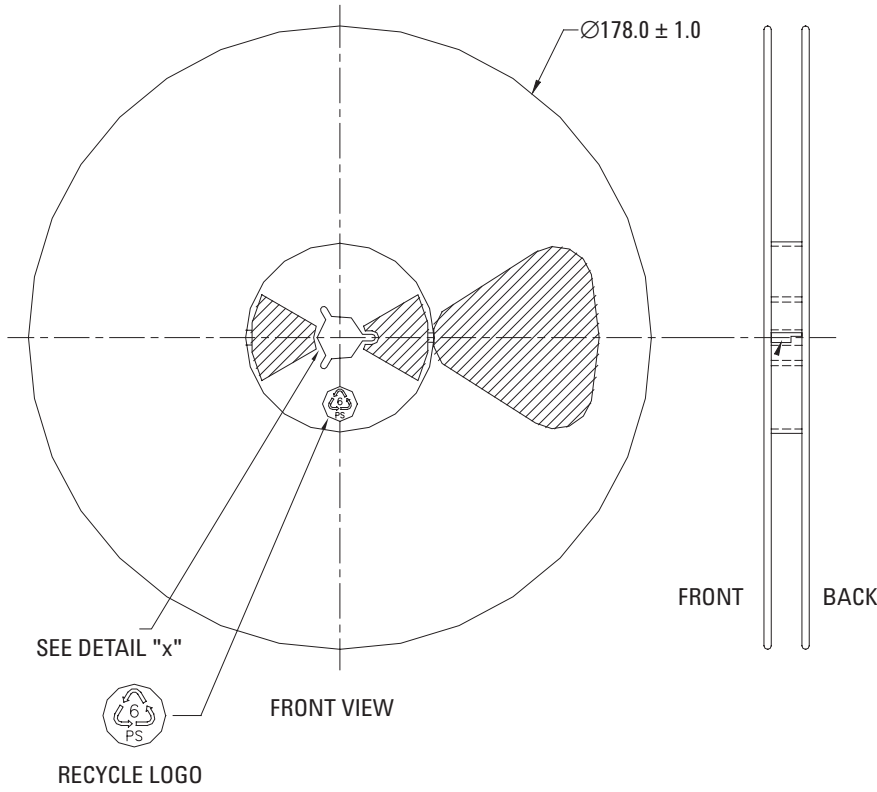
## Tape Dimensions



### Notes:

1. Measured from centerline of sprocket hole to centerline of pocket
  2. Cumulative tolerance of 10 sprocket holes is ± 0.20
- All dimensions in millimeters unless otherwise stated.

# Reel Dimensions



## Part Number Ordering Information

Part Number	No. of Devices	Container
ALM-1106-TR1G	3000	7" Reel
ALM-1106-TR2G	10000	13" Reel
ALM-1106-BLKG	100	antistatic bag

For product information and a complete list of distributors, please go to our web site: [www.avagotech.com](http://www.avagotech.com)

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